



FMMT625

#### 150V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > 150V
- Maximum Continuous Collector Current I<sub>C</sub> = 1A
- 625mW Power Dissipation
- h<sub>FE</sub> Characterised up to 3.0A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (FMMT625Q)

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

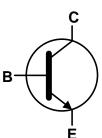
### **Applications**

- DC-DC Modules
- Power Management Functions
- Motor Control and Drive Functions

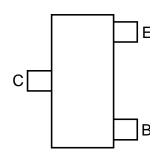








Device Symbol



Top View Pin-Out

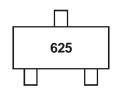
### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FMMT625TA	AEC-Q101	625	7	8	3000 Units

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



625 = Product Type Marking Code



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	150	V
Collector-Emitter Voltage	$V_{\sf CEO}$	150	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	Ісм	3	Α
Base Current	Ι <sub>Β</sub>	500	mA

## Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	625	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	200	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta JL}$	194	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 7)

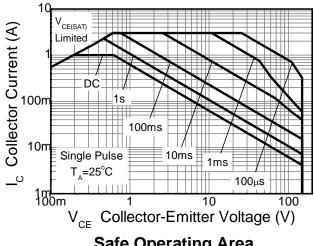
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

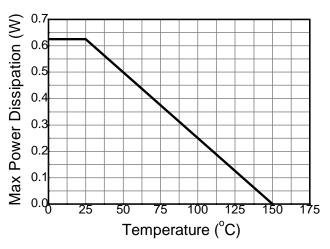
Notes:

- 5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions.
  6. Thermal resistance from junction to solder-point (at the end of the collector lead).
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

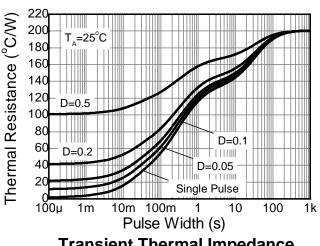


## **Thermal Characteristics and Derating information**

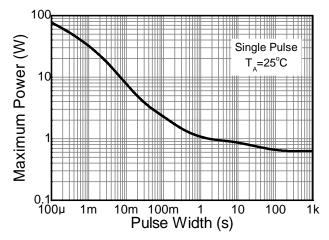








**Derating Curve** 



**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



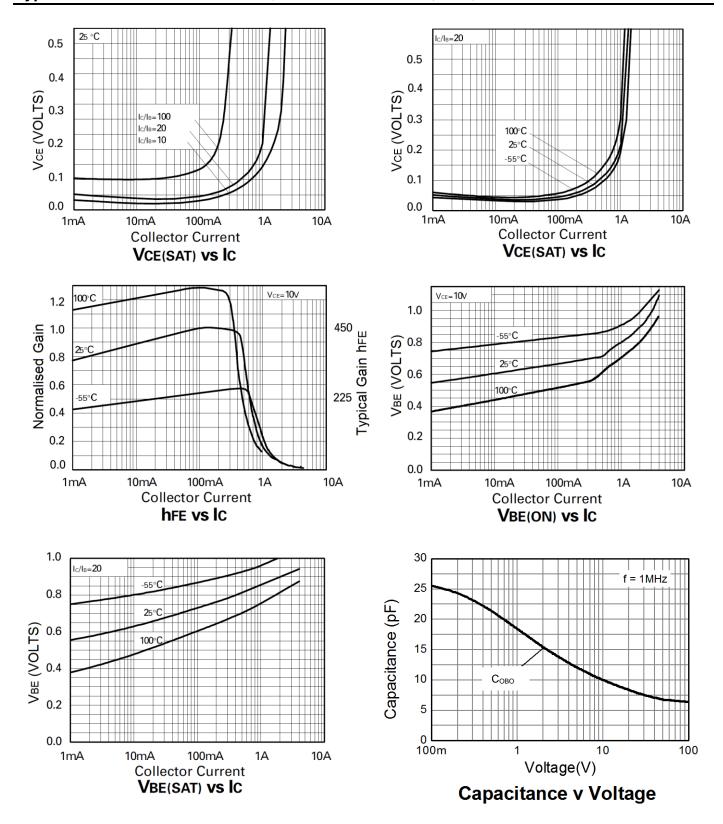
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	300	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	150	175	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	8.3	_	V	$I_E = 100\mu A$
Collector Cut-off Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 130V
Emitter Cut-off Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 5V$
Collector Emitter Cut-off Current	I <sub>CES</sub>	_	_	100	nA	V <sub>CES</sub> = 130V
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	200 300 30 —	400 450 45 15		I	$\begin{split} I_{C} &= 10\text{mA}, \ V_{CE} = 10\text{V} \\ I_{C} &= 200\text{mA}, \ V_{CE} = 10\text{V} \\ I_{C} &= 1\text{A}, \ V_{CE} = 10\text{V} \\ I_{C} &= 3\text{A}, \ V_{CE} = 10\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	VCE(SAT)		26 110 180	50 200 300	mV	$I_C = 0.1A$ , $I_B = 10mA$ $I_C = 0.1A$ , $I_B = 1mA$ $I_C = 1A$ , $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(SAT)</sub>	_	0.85	1.0	V	$I_C = 1A, I_B = 50mA$
Base-Emitter Turn-on Voltage (Note 8)	$V_{BE(ON)}$	_	0.74	1.0	V	$I_C = 1A, V_{CE} = 10V$
Transition Frequency	f <sub>T</sub>	100	135	_	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V},$ f = 100MHz
Collector Output Capacitance	C <sub>OBO</sub>	_	6	10	pF	V <sub>CB</sub> = 10V, f = 1MHz
Turn-On Time	t <sub>(ON)</sub>	_	160	_	ns	$V_{CC} = 50V, I_C = 500mA,$
Turn-Off Time	t <sub>(OFF)</sub>	_	1500	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$

Note 8: Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

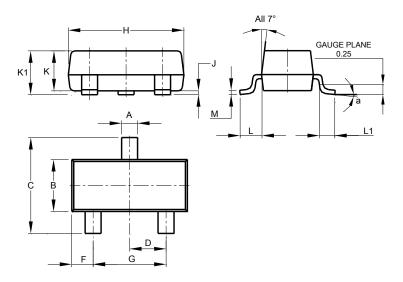




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

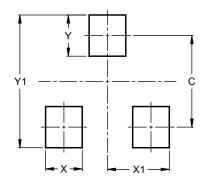


SOT23					
Dim	Min Max		Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		



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